## NSN 5962-01-109-8747

Memory Microcircuit - Page 1 of 1



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Body Le	nath-
0.890 inc	-
Body Wi	
0.290 inc	
Body He	
0.155 inc	
	n Power Dissipation Rating:
1.0 milliw	
	ing Tempurature Range:
	.0 degrees celsius
	Tempurature Range:
	50.0 degrees celsius
	s Provided:
	c and positive outputs and low power and synchronous and w/enable
	e Material:
Plastic	
	e Configuration:
Dual-in-li	
	.ogic Form:
	nentary-metal oxide-semiconductor logic
	rcuit Pattern:
12 input	
	Surface Treatment:
Solder	
	Rating And Type Per Characteristic:
-	power source
Time Ra	ting Per Chacteristic:
	anoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level
output	
	Device Type:
Ram	
	Capacity:
Unknowr	
Termina	I Type And Quantity:
18 printe	
Shelf Lif	e:
N/a	
Unit Of M	Aeasure:
Demilita	rization:
Yes - der	nil/mli
Fiig:	
A458a0	